

Figure 1. XPS spectra of (a) O 1s, (b) F 1s, and (c) Ga 2p_{3/2} for intrinsic Ga₂O₃ and Ga₂O₃ treated with CF₄ plasma at 30 W for 25 s and 2 min.

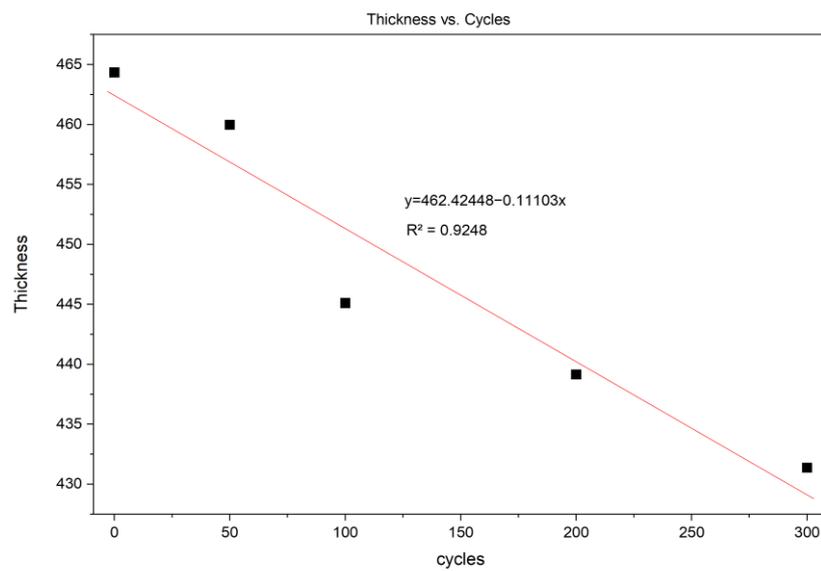


Figure 2. Ga₂O₃ film thickness vs cycle number of pALE at 450°C